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crosstalk

FSA641 — 2:1 MIPI Switch, Featuring 2-Data and 1-Data Lane Configuration

Description

distortion.

minimizes interference.

Related Resources

FSA641 Demonstration Board

The FSA641 is a 2:1 MIPI switch made for 2-data lane

and 1-data lane modules. This part is configured as a

single-pole, double-throw switch (SPDT) and is optimized for switching between two high-speed or low-power MIPI

sources. The FSA641 has specially been designed for the

MIPI specification and allows connection to either a CSI or DSI module. The FSA641 features an extremely low on

capacitance (CON) of 8 pF. The wide bandwidth (1 GHz)

results in signals with minimum edge and phase

channel-to-channel

Superior

 For samples and questions, please contact: Analog.Switch@fairchildsemi.com.

Features

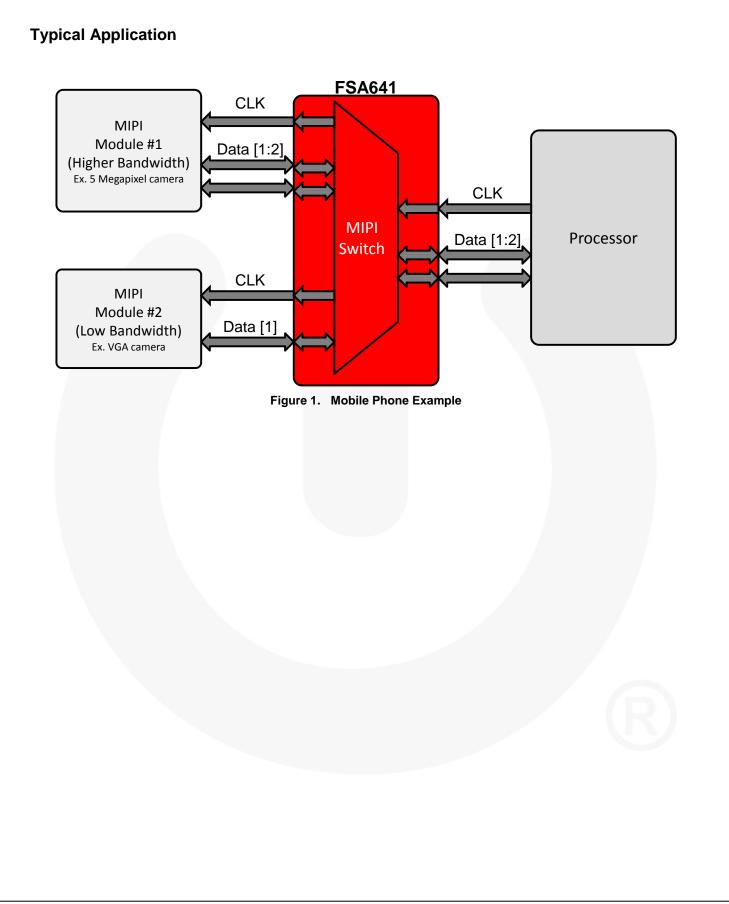
- Switch Type: 2:1
- Signal Types MIPI, DPHY
- V_{CC}: 2.65 to 4.3 V
- Input Signals 0 to V_{CC}
- Ron:
 - 7 Ω Typical HS MIPI
 - 10 Ω Typical LS MIPI
- ΔR_{ON}: 0.75 Ω Typical HS & LS MIPI
- I_{cc}: 1 µA Maximum
- OIRR: -50 dB Typical
- X_{TALK}: -40 dB Typical
- Bandwidth: 1 GHz Typical
- Channel-to-Channel Skew: 15 ps Typical
- C_{ON}: 8 pF Typical
- Package 20-Lead UMLP

Applications

- Cellular Phones, Smartphones
- Displays

Ordering Information

Part Number	Top Mark	Operating Temperature Range	Package
FSA641UMX	F641	-40 to +85°C	20-Lead, Quad, Ultrathin Molded Leadless Package (UMLP), 3.0 x 3.0 mm



Pin Configuration

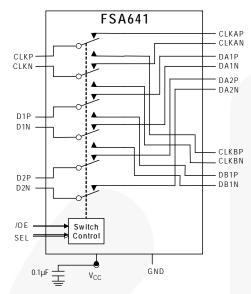
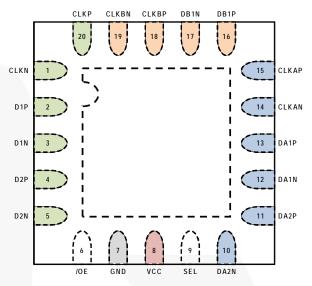
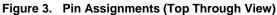


Figure 2. Functional Block Diagram





Pin Descriptions

Pin #	Pin Name	Туре	Description		
20	CLKP	I/O	Common positive clock path		
1	CLKN	I/O	Common negative clock path		
2	D1P	I/O	Common positive data 1 path		
3	D1N	I/O	Common negative data 1 path		
4	D2P	I/O	Common positive data 2 path		
5	D2N	I/O	Common negative data 2 path		
15	CLKAP	I/O	A-port positive clock path		
14	CLKAN	I/O	A-port negative clock path		
13	DA1P	I/O	A-port positive data 1 path		
12	DA1N	I/O	A-port negative data 1 path		
11	DA2P	I/O	A-port positive data 2 path		
10	DA2N	I/O	A-port negative data 2 path		
18	CLKBP	I/O	B-port positive clock path		
19	CLKBN	I/O	B-port negative clock path		
16	DB1P	I/O	B-port positive data 1 path		
17	DB1N	I/O	B-port negative data 1 path		
6	/OE	Input	Output Enable (Active Low)		
7	GND	Ground	Ground		
8	VCC	Supply	Power; 0.1 µF decoupling capacitor to ground recommended		
9	SEL	Input	A-port or B-port Select pin 0=A-port, 1= B-port		
Paddle	n/a	NC	Not Connected		

Truth Table

SEL	/OE	Function
Don't Care	HIGH	Disconnect
LOW	LOW	D1, D2, CLK=DA1, DA2, CLKA
HIGH	LOW	D1, CLK=DB1, CLKB; D2 OPEN

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
Vcc	Supply Voltage		-0.50	+5.25	V
V _{CNTRL}	DC Input Voltage (SEL, /OE) ⁽¹⁾		-0.5	V _{CC}	V
V _{SW}	DC Switch I/O Voltage ⁽¹⁾		-0.5	V _{CC} + 0.3	V
Іік	DC Input Diode Current		-50		mA
I _{OUT}	DC Output Current			50	mA
T _{STG}	Storage Temperature		-65	+150	°C
		All Pins		6.5	
ESD	Human Body Model, JEDEC: JESD22-A114	I/O to GND		8.0	kV
LOD		Power to GND		16.0	κv
	Charged Device Model, JEDEC: JESD22-C101			2.0	

Note:

1. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
Vcc	Supply Voltage	2.65	4.30	V
V _{CNTRL}	Control Input Voltage (SEL, /OE) ⁽²⁾	0	V _{CC}	V
Vsw	Switch I/O Voltage	-0.5	V _{cc} -1 V	V
T _A	Operating Temperature	-40	+85	°C

Note:

2. The control input must be held HIGH or LOW; it must not float.

DC Electrical Characteristics

All typical values are T_A=25°C unless otherwise specified.

Symbol	Deremeter	Conditions	V 00	T _A =∙	-40 to +	85⁰C	Units
Symbol	Parameter	Conditions	Conditions V _{cc} (V)	Min.	Тур.	Max.	Units
V _{IK}	Clamp Diode Voltage	I _{IN} =-18 mA	2.775			-1.2	V
I _{IN}	Control Input Leakage	V _{SW} =0 to 4.3 V	4.3	-1		1	μA
V	Input Voltage High	$\lambda = 0$ to $\lambda = 0$	2.650 to 2.775	1.3			v
V _{IH}		V _{IN} =0 to V _{CC}	4.3	1.7			V
VIL	Input Voltage Low	V _{IN} =0 to V _{CC}	2.650 to 2.775			0.5	V
l _{oz}	Off-State Leakage	A, B=0+0.3 V to V _{CC} -0.3	4.3	-2		2	μA
Icc	Quiescent Supply Current	V _{CNTRL} =0 or V _{CC} , I _{OUT} =0	4.3			1.0	μA
I _{CCT}	Increase in I_{CC} Current Per Control Voltage and V_{CC}	V _{CNTRL} =1.8 V	2.775			1.5	μA

DC Electrical Characteristics, Low-Speed Mode

All typical values are $T_A=25^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	ns V _{cc} (V) ——	T _A =-	40 to +	-85⁰C	Units
Cymbol	i di difictei	Conditions		Min.	Тур.	Max.	onits
R _{ON}	LS Switch On Resistance ⁽³⁾	V_{SW} =1.2 V, I _{ON} =-10 mA, Figure 4	2.65		10	14	Ω
ΔR_{ON}	LS Delta R _{ON} ⁽⁴⁾	V _{SW} =1.2 V, I _{ON} =-10 mA (Intra-pair)	2.65		0.75		Ω

Notes:

3. Measured by the voltage drop between A/B and CLK/Dn pins at the indicated current through the switch.

4. Guaranteed by characterization.

DC Electrical Characteristics, High-Speed Mode

All typical values are T_A=25°C unless otherwise specified.

Symbol	Parameter	Conditions	V _{cc} (V)	T _A =-	40 to +	.85⁰C	Units
Symbol	Farameter	Conditions	▼cc (▼)	Min.	Тур.	Max.	Units
R _{ON}	HS Switch On Resistance ⁽⁵⁾	$V_{\text{SW}} {=} 0.4$ V, $I_{\text{ON}} {=} {-} 10$ mA, Figure 4	2.65		7.0	9.5	Ω
ΔR_{ON}	HS Delta R _{ON} ⁽⁶⁾	V _{SW} =0.4 V, I _{ON} =-10 mA (Intra-pair)	2.65		0.75		Ω

Notes:

5. Measured by the voltage drop between A, B, and Dn pins at the indicated current through the switch.

6. Guaranteed by characterization.

AC Electrical Characteristics

All values are at R_L=50 Ω and R_S=50 Ω and all typical values are V_{CC}=2.775 V at T_A=25°C unless otherwise specified.

Symbol	Deremeter	Conditions	V 00	T _A =-4	40ºC to +	-85⁰C	Unito
Symbol	Parameter	Conditions	V _{cc} (V)	Min.	Тур.	Max.	Units
O _{IRR}	Off Isolation ⁽⁷⁾	f=100 MHz, R_T =50 Ω Figure 14	2.775		-50		dB
Xtalk	Non-Adjacent Channel Crosstalk ⁽⁷⁾	f=100 MHz, R_T =50 Ω Figure 15	2.775		-40		dB
BW	-3db Bandwidth ⁽⁷⁾	$C_L=0 \text{ pF}, R_T=50 \Omega$ Figure 13	2.775		1.0		GHz
t _{ON}	Turn-On Time SEL, /OE to Output	$C_L=5 \text{ pF}, V_{SW}=1.2 \text{ V}$ Figure 6, Figure 7	2.650 to 2.775		20	37	ns
t _{OFF}	Turn-Off Time SEL, /OE to Output	C_L =5 pF, V _{SW} =1.2 V Figure 6, Figure 7	2.650 to 2.775		15	27	ns
t _{PD}	Propagation Delay ⁽⁷⁾	C∟=5 pF Figure 6, Figure 8	2.775		0.25		ns
t _{BBM}	Break-Before-Make Time	$\begin{array}{c} C_{L} = 5 \text{ pF}, V_{SW1} = V_{SW2} = 1.2 \text{ V} \\ \text{Figure } 12 \end{array}$	2.650 to 2.775	7	9	12	ns

Note:

7. Guaranteed by characterization.

AC Electrical Characteristics, High-Speed

All typical values are V_{CC}=2.775 V at T_A=25°C unless otherwise specified.

Symbol	Peremeter	Conditions	T _A =-4	40ºC to +	-85⁰C	Unito
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
t _{SK(Part_Part)}	Channel-to-Channel Skew Across Multiple Parts ^(8,9)	TDR-Based Method (V _{SW} -0.2V _{PP} ,C _L =C _{ON})		40	80	ps
t _{SK(ChI_ChI)}	Channel-to-Channel Skew Within a Single Part ⁽⁸⁾	TDR-Based Method (V _{SW} -0.2V _{PP} ,C _L =C _{ON})		15	30	ps
t _{SK(Pulse)}	Skew of Opposite Transitions in the Same Differential Channel ⁽⁸⁾	TDR-Based Method (V _{SW} -0.2V _{PP} ,C _L =C _{ON})		10	20	ps

Notes:

8. Guaranteed by characterization.

9. Assumes the same V_{CC} and temperature for all devices.

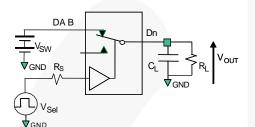
Capacitance

Cumhal	Deremeter	Conditions	T _A =-40°C to +85°C			Unito
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
C _{IN}	Control Pin Input Capacitance ⁽¹⁰⁾	V _{CC} =0 V		1.5		
C _{ON}	Dn/CLK- On Capacitance ⁽¹⁰⁾	V _{CC} =2.775 V, /OE=0V, f=1 MHz Figure 11		8.0		pF
C _{OFF}	Dn/CLK Off Capacitance ⁽⁹⁾	V _{CC} =2.775 V, /OE=2.775 V, f=1 MHz Figure 10		2.5		

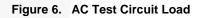
Note:

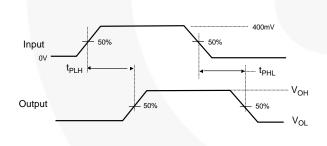
10. Guaranteed by characterization.

Test Diagrams VON DA/Bn SW Select _{el}= 0 orVcc $R_{ON} = V_{ON} / I_{ON}$ Figure 4. On Resistance

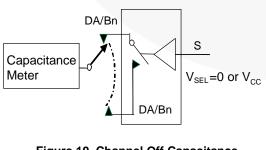


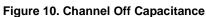
 R_L, R_S , an C_L ar fu ctions of the ap lication environment (se AC Tables for spe ific v lues) CL inclu es test fixture an stra capacitance

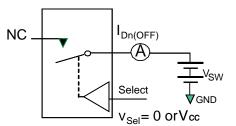












**Each switch port is tested separately

Figure 5. Off Leakage

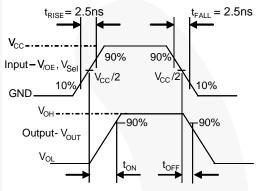


Figure 7. Turn-On / Turn-Off Waveforms

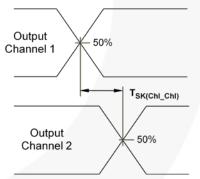
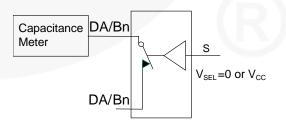
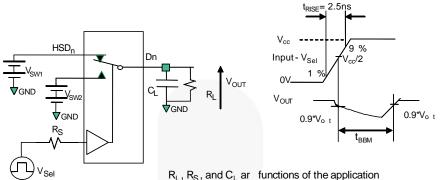


Figure 9. Channel-to-Channel Skew



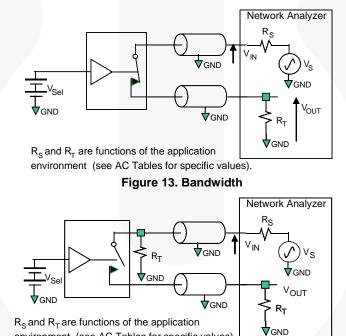


Test Diagrams (Continued)



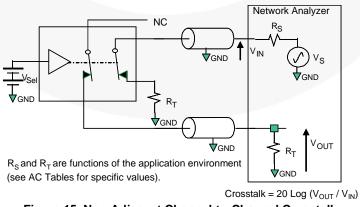
 R_L , R_S , and C_L ar functions of the application environment (see AC Tables for specific values). C_L includes test fixture and stray capacitance.





environment (see AC Tables for specific values). V_{GND} Off isolation = 20 Log (V_{OUT} / V_{IN})

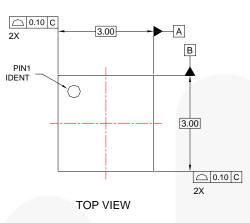
Figure 14. Channel Off Isolation

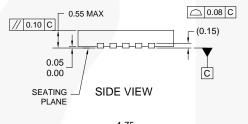


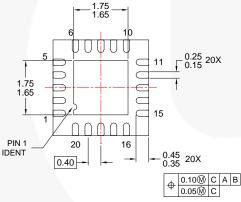




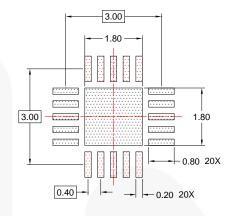
Physical Dimensions







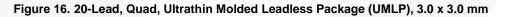




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- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
- D. LAND PATTERN RECOMMENDATION IS FROM PCB MATRIX CALCULATOR V2009.
- E. DRAWING FILENAME: MKT-UMLP20Brev1.



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Rev. 168

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